SLVS185 – FEBRUARY 2000

- $\bullet$ **Li-Ion Battery Charging Control**
- $\bullet$ **Over-Voltage Shutdown**
- $\bullet$  **Seven Low-Dropout Low-Noise Linear Voltage Regulators (LDO)**
- $\bullet$ **Voltage Detectors (With Power-Off Delay)**
- $\bullet$ **Four-Channel Analog Multiplexer**
- $\bullet$  **Three General-Purpose Operational Amplifiers**
- $\bullet$ **Ringer Driver**
- $\bullet$ **Power Supply Switch for Accessories**
- $\bullet$ **Low Quiescent Current**
- $\bullet$ **48-pin TQFP**



### **description**

The TWL2203 incorporates a complete power-management system for a cellular telephone that uses lithium-ion cells. The device includes circuitry to control the gate voltage of two P-channel MOSFETs. The MOSFETs perform constant-voltage/constant-current charging (CVCC). The TWL2203 has seven low-drop linear voltage regulators (LDO) to regulate the battery power supply to the different sections of the phone, a battery voltage monitor, a ringer driver, an analog multiplexer, and three general-purpose operational amplifiers for signal conditioning.

The TWL2203 is packaged in TI's 48-pin thin-quad flat package (PFB).



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SLVS185 – FEBRUARY 2000



## **functional block diagram**





SLVS185 – FEBRUARY 2000

## **Terminal Functions**



SLVS185 – FEBRUARY 2000

## **Terminal Functions (Continued)**



### **detailed description**

#### **battery-charging control**

The battery charging control block in the device is a part of the lithium-ion battery (Li-Ion) charging system of the phone. It is capable of regulating the external power source to charge the lithium-ion battery according to the battery-charging requirements. More information on battery-charging control is presented in the application information section.

The MOSFET driver and its feedback-control circuit are enabled/disabled by a CMOS control signal provided by the phone's microprocessor. The maximum-charging current is set by external resistors for design flexibility.

#### **overvoltage shutdown**

The device shuts down the charging circuit in the presence of an overvoltage condition.

#### **low-dropout linear voltage regulators**

The device has seven separate low-dropout linear-voltage regulators. A single enable signal controls four of the regulators. The last three regulators are controlled by their own enable signals.

#### **voltage detectors (with power-off delay)**

The device has two voltage detectors. The voltage detectors monitor the voltage level of the external power and  $V_{CC}$ . The external power detector (VDET1) has a CMOS output. The  $V_{CC}$  detector (VDET2) activates on the falling edge and has user-adjustable power-off delay. There is an internal pullup resistor on the output.

### **analog multiplexer**

The device has a four-channel analog multiplexer with two-bit channel-selector signal input and a shutdown function. In the shutdown mode, all the input and output terminals are in the high-impedance state.

#### **operational amplifiers**

The device has three rail-to-rail operational amplifiers with common shutdown control.

#### **power supply switch for external phone accessories**

The device provides current-limited voltage supply to the external phone accessories via the external-interface connector. The power supply switch is controlled by the same enable signal (EN1) that controls the four regulators—LDO1-LDO4. The external phone accessories are resistive in nature.

#### **ringer driver**

The device is capable of driving a ringer. It is controlled by a CMOS signal, and uses an N-channel low-side driver.



SLVS185 – FEBRUARY 2000

### **DISSIPATION-RATING TABLE – FREE-AIR TEMPERATURE**



### **absolute maximum ratings over operating free-air temperature (unless otherwise noted)†**



† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **recommended operating conditions**



### electrical characteristics over recommended operating junction temperature range, V<sub>CC</sub> = 3.75 V **and VEXT = 5.5 V (unless otherwise specified)**

### **current table,**  $T_A = -40^\circ \text{C}$  **to 85°C**



SLVS185 – FEBRUARY 2000

## **battery charging control,**  $T_A = 0^\circ \text{C}$  **to 50** $^\circ \text{C}$



## **over-voltage shutdown, TA = 0**°**C to 50**°**C**





SLVS185 – FEBRUARY 2000

### electrical characteristics over recommended operating junction temperature range, V<sub>CC</sub> = 3.75 V **and VEXT = 5.5 V (unless otherwise specified) (continued)**



## LDO regulator 1 (LCD Module),  $T_A = -20^\circ \text{C}$  to 85 $^\circ \text{C}$

## LDO regulator 2 (Digital),  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$



## LDO regulator 3 (TCX0),  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$



## LDO regulator 4 (Audio),  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$





SLVS185 – FEBRUARY 2000

### electrical characteristics over recommended operating junction temperature range, V<sub>CC</sub> = 3.75 V **and VEXT = 5.5 V (unless otherwise specified) (continued)**

## LDO regulator 5 (RX),  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$



## LDO regulator 6 (TX),  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$



## LDO regulator 7 (PLL),  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$



† With external filtering

## $VDET1, T_A = 25$ <sup>°</sup>C





SLVS185 – FEBRUARY 2000

### electrical characteristics over recommended operating junction temperature range, V<sub>CC</sub> = 3.75 V **and VEXT = 5.5 V (unless otherwise specified) (continued)**

## $V$ **DET2, T<sub>A</sub> = 25<sup>°</sup>C**



### **power switch,**  $T_A = 25^{\circ}C$



## analog multiplexer,  $T_A = -30^\circ \text{C}$  to  $85^\circ \text{C}$





SLVS185 – FEBRUARY 2000

### electrical characteristics over recommended operating junction temperature range, V<sub>CC</sub> = 3.75 V **and VEXT = 5.5 V (unless otherwise specified) (continued)**

## **operational amplifiers,**  $T_A = -30^\circ \text{C}$  **to 85** $^\circ \text{C}$



# **ringer driver,**  $T_A = -30^\circ \text{C}$  **to 85 °C**



#### **internal power supply**



### **bandgap reference**



### **thermal shutdown**





### **THERMAL INFORMATION**

The implementation of integrated circuits in low-profile and fine-pitch surface-mount packages requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the powerdissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below.

- $\bullet$ Improving the power dissipation capability of the printed-circuit board design
- $\bullet$ Improving the thermal coupling of the component to the printed-circuit board
- $\bullet$ Introducing airflow into the system

Using the given  $R_{\theta JA}$  for this device, the maximum power dissipation can be calculated with the equation:

$$
P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{R_{\theta JA}}
$$

### **APPLICATION INFORMATION**

#### **capacitor selection**

The output bypass capacitor of each LDO regulator should be selected from the list of ceramic capacitors shown below. The VCC bypass capacitors should be selected from the list of tantalum capacitors shown below. Tantalum capacitors have good temperature stability and offer good capacitance for their size. Care should be taken when using marginal quality tantalum capacitors, as the increase of the equivalent series resistance (ESR) at low temperatures can cause instability. For a given capacitance, ceramic capacitors are usually larger and more costly than tantalums. The capacitance of ceramic capacitors varies greatly with temperature. In addition, the ESR of ceramic capacitors can be low enough to cause instability. A low-value resistor can be added in series with the ceramic capacitor to provide a minimum ESR.

#### **ceramic (X7R or X5R)**



#### **tantalum (6.3 V rating)**





SLVS185 – FEBRUARY 2000

## **APPLICATION INFORMATION**

## **recommended parts list**





SLVS185 – FEBRUARY 2000

### **APPLICATION INFORMATION**

### **battery charging control**





SLVS185 – FEBRUARY 2000

## **APPLICATION INFORMATION**

### **battery-charging control (continued)**

The battery-charging control block in the device is a part of the Li-Ion battery charging system of the phone. The device controls the P-channel MOSFET to accomplish constant-voltage/constant-current charging (CVCC) within a  $\pm$ 1% tolerance in the charging termination voltage.

The battery charging control consists of the two sections:

- $\bullet$ CVCC charge-switch control with feedback loops for voltage and current control
- $\bullet$ Trickle charge-current control

When the voltage-detector output (DET1) is set high, the voltage-control loop is activated to regulate the voltage of ICH- to 4.2 V. Then, when the control signal input CH is set high, either the current-control loop or the trickle-charge control block is activated, depending upon battery voltage.

When VB is below the threshold Vtc, the trickle-charge current control block directs the current to the battery via TCIN, trickle-charging current control, TCOUT, R6, and the battery. The measure of the voltage across sense resistor R6 is used for feedback-control of the rate of charging current.

Once the battery voltage reaches the threshold Vtc, the CVCC charge-switch control block becomes active and controls the P-channel MOSFET M1. The feedback control ensures that the voltage ICH- does not exceed 4.2  $V \pm 0.05$  V (4.2 V regulation), and the current draw of resistor R1 does not exceed the specified value (current-limit control). In this case, the charging current drains via R1, M2, and the battery. The maximum charging current is set by external resistors for design flexibility.

### **analog multiplexer output table**





SLVS185 – FEBRUARY 2000

### **MECHANICAL DATA**

**PFB (S-PQFP-G48) PLASTIC QUAD FLATPACK**



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-026



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